Temperature dependent local atomic displacements in Ru substituted $SmFe_{1-x}Ru_xAsO_{0.85}F_{0.15}$ superconductors

Boby Joseph,¹ Antonella Iadecola,^{1,2} Laura Simonelli,³ Laura Maugeri,¹

Alberto Martinelli,⁴ Andrea Palenzona,⁴ Marina Putti,⁴ and Naurang L. Saini¹

¹Dipartimento di Fisica, Università di Roma "La Sapienza", P. le Aldo Moro 2, 00185 Roma, Italy

²Elettra, Sincrotrone Trieste, Strada Statale 14, Km 163.5, Basovizza, Trieste, Italy

³ European Synchrotron Radiation Facility, 6 RUE Jules Horowitz BP 220 38043 Grenoble Cedex 9 France

⁴CNR-SPIN and Università di Genova, via Dodecaneso 33, 16146 Genova, Italy

Local structure of SmFe_{1-x}Ru_xAsO_{0.85}F_{0.15} (x = 0.0, 0.05, 0.25 and 0.5) superconductors has been investigated by temperature dependent As K-edge extended x-ray absorption fine structure. The effect of Ru substitution remains confined to the iron-arsenide layer but neither the static disorder nor the Fe-As bond strength suffers any change for $x \leq 0.25$. With further Ru substitution the static disorder increases while the Fe-As bond strength remains unchanged. Also, the Ru-As distance (~2.42 Å), different from the Fe-As distance (~2.39 Å), does not show any change in its force constant with the Ru substitution. These observations suggest that the SmFe_{1-x}Ru_xAsO_{0.85}F_{0.15} system breaks down to coexisting local electronic phases on isoelectric substitution in the active FeAs layer.

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I. INTRODUCTION

The newly discovered iron-based high T_c superconductors [1–3] have a particular layered structure with electronically active FePn/Ch (Pn = pnictogen; Ch = chalcogen) layers alternated by spacer layers. The superconductivity and magnetism in these materials are strongly dependent on the thickness of the active layers (e.g., the height of Pn/Ch atoms from the Fe-plane) [3]. Among the iron-based superconductors, the REFeAsO (RE=rare earth), the socalled 1111 system with well defined iron-arsenide active layers stacked together with the spacer layers shows the highest T_c [2, 3]. Generally, atomic substitution in either of the stacking layers is used to control and manipulate superconductivity and other transport properties (e.g., a partial substitution of O by F) [3]. In addition to the control over the superconductivity, atomic substitution in the active layer also permits to understand the transport phenomena [4, 5] and develop new structures through a detailed information on the role of different layers. In particular, it is important to have knowledge of the local atomic correlations and modification introduced by the substituted atoms in the layered structure topology.

X-ray absorption spectroscopy is an atomic site-specific experimental probe [6], that does not require any long range crystal symmetry, and hence permits to have a direct access to the local atomic correlations. Indeed, x-ray absorption fine structure (EXAFS) and x-ray absorption near edge structure (XANES) measurements have been widely exploited to study the layered high T_c superconductors [7–10], including the iron based superconductors [11–19]. Earlier, we have explored the effect of different spacer layers (RE of different size) in the 1111-system [13, 14], and found that the interlayer atomic order/disorder should be important in these materials. We have also studied the effect of charge density varied by a partial substitution in the REO spacer layers (O by F), revealing key information on the interlayer atomic correlations and dynamics [16]. Recently we have focussed on the effect of isovalent Ru (atomic radius 1.34 Å) substitution directly in the active FeAs layer in place of Fe (atomic radius 1.26 Å) of an optimally doped $SmFe_{1-x}Ru_xAsO_{0.85}F_{0.15}$ [19]. The results have revealed that the local disorder induced by the Ru substitution is mainly confined to the FeAs layers which are getting thinner and decoupled from the SmO spacer layers. The present work is dedicated to distinctly identify the random static disorder and the bondlength fluctuations induced by an isoelectric substitution in the iron-arsenide active layer. For the purpose, we have performed temperature dependent As *K*-edge EXAFS measurements on a series of $SmFe_{1-x}Ru_xAsO_{0.85}F_{0.15}$ (x = 0.0, 0.05, 0.25 and 0.5) samples. Consistent with earlier work [19], the Ru substituted system is found to be characterized by different Fe-As and Ru-As distances. Incidentally, the force constants for these distances remain unchanged with increasing Ru substitution, indicating distinct local electronic phases coexisting in the system. It appears that the system breaks down to coexisting nanoscale electronic phases due to isoelectric substitution, having a direct influence on the fundamental electronic properties of these materials.

II. EXPERIMENTAL DETAILS

The As K-edge (E = 11868 eV) x-ray absorption measurements on powder samples of SmFe_{1-x}Ru_xAsO_{0.85}F_{0.15} (x = 0.0, 0.25 and 0.5) were performed in transmission mode at the beamline BM26A [20] of the European Synchrotron Radiation Facility (ESRF), Grenoble. Measurements on the x = 0.05 sample were carried out at the XAFS beamline of the ELETTRA, Trieste using similar experimental approach. Temperature dependent measurements were carried out between 10 to 300 K. Several scans were acquired at each temperature to ensure the spectral reproducibility. The EXAFS oscillations were extracted using the standard procedure based on spline fit to the pre-edge subtracted absorption spectrum [6]. The superconducting transition temperatures (T_c), determined by resistivity measurements, are 51 K, 43 K, 14 K and 8 K respectively for the samples with x = 0.0, 0.05, 0.25 and 0.5. Details on the sample preparation and characterization for transport and structural properties are described elsewhere [21–24].

III. RESULTS AND DISCUSSIONS

Figure 1 shows k^2 weighted arsenic K-edge EXAFS of SmFe_{1-x}Ru_xAsO_{0.85}F_{0.15} (x = 0.0, 0.05, 0.25 and 0.5) at several temperatures. The effect of temperature and Ru substitution is evident from the EXAFS oscillations. For example, temperature dependent damping of EXAFS signal can be seen for all the samples. Similarly, the effect of Ru substitution can be seen in the EXAFS oscillations (see, e.g., $k \ge 6 \text{ Å}^{-1}$). These effects can be better appreciated in the Fourier transforms of the EXAFS, providing real space information on the partial atomic distribution around the As atoms.

Figure 2 shows the Fourier transform (FT) magnitudes, obtained using a Gaussian window (k-range of EXAFS is 3-18 Å⁻¹). There are four Fe/Ru near neighbours of arsenic at a distance ~ 2.4 Å (the main peak at ~ 2 Å). The next nearest neighbours of arsenic are Sm atoms at ~ 3.3 Å and O/F atoms at ~ 3.5 Å follwed by the As atoms at



FIG. 1: Arsenic K-edge EXAFS of $SmFe_{1-x}Ru_xAsO_{0.85}F_{0.15}$ (x = 0.0, 0.05, 0.25 and 0.5) at several temperatures (weighted with k^2). The evolution of the local structure with temperature and Ru concentration is apparent from the EXAFS oscillations.

~ 3.9 Å (the two peaks between 3-4 Å), mixed with the multiple scattering contribution due to Fe/Ru (~ 4.6 Å), appearing as FT peak at ~ 4.2 Å (see, e.g. top panel). It can be seen that the main FT peak is changing with Ru substitution while other FT peaks due to next near neighbour atoms suffering much smaller (or negligible) changes. Indeed, the main peak decreases substantially with Ru and appears as a clear doublet structure in the x = 0.5 sample. Similarly, the multiple scattering Fe/Ru peak at ~ 4.2 Å sustains large change, having negligible weight in the x = 0.5 sample. All these data are suggesting that the atomic disorder due to Ru substitution is mainly confined to the active layer, consistent with the earlier study [19]. On the other hand, the temperature dependent damping of the FT peaks appears almost similar in all the samples.



FIG. 2: Fourier transform magnitudes of the arsenic K-edge EXAFS at low and high temperatures (symbols) together with As-Fe/As-Ru shells model fits (solid lines) for the SmFe_{1-x}Ru_xAsO_{0.85}F_{0.15} system. Insets show the filtered EXAFS oscillations (symbols) and the corresponding model fits (solid lines).

In the single-scattering approximation, the EXAFS is described by the following general equation [6]:

$$\chi(k) = \sum_{i} \frac{N_i S_0^2}{kR_i^2} f_i(k, R_i) e^{-\frac{2R_i}{\lambda}} e^{-2k^2 \sigma_i^2} \sin[2kR_i + \delta_i(k)]$$

where N_i is the number of neighbouring atoms at a distance R_i from the photoabsorbing atom. Here, S_0^2 is the passive electrons amplitude reduction factor, $f_i(k,R_i)$ is the backscattering amplitude, λ is the photoelectron mean free path, δ_i is the phase shift, and σ_i^2 is the correlated Debye-Waller factor measuring the mean square relative displacement (MSRD) of the photoabsorber-backscatter pairs.

For the As K-edge EXAFS in the SmFe_{1-x}Ru_xAsO_{0.85}F_{0.15}, the first shell contribution involves only the Fe-As/Ru-As bonds, well separated from all other distant atom contributions [11, 12, 16, 19]. To quantify the temperature dependent atomic displacements we have analyzed the EXAFS only due to the nearest neighbours. The filtered first shell EXAFS are displayed as insets of the Fig. 2. In the model fits we have varied the Fe-As/Ru-As distances and the corresponding σ_i^2 , while other parameters including the photo-electron energy origin E₀ (a value obtained by modeling five different scans at low temperature), the number of near neighbors N_i (an input from diffraction studies [21, 23]) and S₀² (=1.0) were all kept fixed for the final iteration. Phase shifts and amplitude factors were calculated using the



FIG. 3: Temperature dependence of Fe-As (upper four panels) and Ru-As (lower two panels) distances for the $SmFe_{1-x}Ru_xAsO_{0.85}F_{0.15}$ (x = 0.0, 0.05, 0.25 and 0.5) determined by As K-edge EXAFS analysis.

FEFF [25]. The number of independent data points for this analysis were about 11 ($N_{ind} \sim (2\Delta k\Delta R)/\pi$, where $\Delta k = 15$ Å⁻¹ and $\Delta R = 1.2$ Å are the k and R space over which the data have been analyzed) for a maximum of four parameters fits to the filtered EXAFS. The k-space (insets) and R-space model fits are also included in Fig. 2. The errors in the local structural parameters, determined by the EXAFS analysis, are estimated by creating correlation maps between different parameters and by analysis of different scans that are measured in the same conditions, following the known standards [26].

Figure 3 shows near neighbour (Fe-As and Ru-As) distances as a function of temperature, obtained from the EXAFS analysis. The related σ_i^2 are shown in Fig. 4. The Fe-As distance (~2.39 Å) is different from the Ru-As distance (~2.42 Å) with the difference (~0.03 Å) being smaller than that measured in isostructural compounds like RuAs-



FIG. 4: Temperature dependence of mean square relative displacements in $\text{SmFe}_{1-x}\text{Ru}_x\text{AsO}_{0.85}\text{F}_{0.15}$ (x = 0.0, 0.05, 0.25, and 0.5) for the Fe-As (empty symbols) and Ru-As (filled symbols) bondlengths. The dotted lines are the correlated Einstein model fits.

FeAs and RuAs₂-FeAs₂ (~0.06 Å) [27]. This suggests the active layer in SmFe_{1-x}Ru_xAsO_{0.85}F_{0.15} is under chemical pressure from the REO spacter layer. Within the experimental uncertainties the local Fe-As (and Ru-As) distance remains constant with temperature and Ru concentration, consistent with strongly covalent nature of the Fe-As (and Ru-As) bonds that is known from earlier studies [13]. It is worth recalling that the reported error bars represent the maximum uncertainty (that is much higher than actual errors in most of the data points), that are determined by considering correlation between the fit parameters, i.e. the distances R_i and the σ_i^2 .

The temperature dependence of the σ_i^2 permits to distinctly identify the random static disorder and the dynamic atomic displacements. The EXAFS σ_i^2 is a sum of temperature independent (σ_0^2) and temperature dependent σ_i^2 (T)

terms [6], i.e.,

$$\sigma_i^2 = \sigma_0^2 + \sigma_i^2(T)$$

The temperature dependent term can be described by the correlated Einstein-model [28, 29],

$$\sigma_i^2(T) = \frac{\hbar}{2\mu\omega_E} \coth(\frac{\hbar\omega_E}{2k_BT}),$$

where μ is the reduced mass and ω_E is the Einstein-frequency of the pair of atoms involved (i.e., Fe-As and Ru-As bonds). The related Einstein-temperature is $\Theta_E = \hbar \omega_E / k_B$. The fits to the correlated Einstein model are shown as dotted lines in Fig. 4. The Θ_E for the Fe-As bonds are found to be 324 ± 17 K, 323 ± 20 K, 321 ± 24 K and 316 ± 20 K for the x = 0.0, 0.05, 0.25 and 0.5 samples respectively. The optical phonon modes in SmFeAsO are 201 cm⁻¹ (A_{1g}) involving As atom displacements) and 208 cm⁻¹ (B_{1q} involving Fe atom displacements) [30, 31]. These frequencies are quite similar to the EXAFS findings, the Einstein frequency of the Fe-As to be about 225 cm⁻¹ ($\Theta_E \sim 324$ K). The Θ_E for the Fe-As bonds are lower than the Θ_E for the Ru-As bonds. The Θ_E for the Ru-As bonds are found to be 353 ± 42 K and 354 ± 26 K respectively for the x=0.25 and x=0.5 samples. The σ_0^2 representing the random static disorder, is significantly higher for the x=0.5 sample, ~ 0.0026 Å², compared to ~ 0.0006 Å² for x=0.0, 0.05 and 0.25 samples. Similar static disorder and force constants (5.09, 5.06 and 4.99 eV/Å² respectively) for the Fe-As bonds in x = 0.0, 0.05 and 0.25 indicate that the atomic disorder in the FeAs layer may not have a direct effect the electronic transport. Indeed, the residual resistivity ρ_0 changes anomalously as a function of Ru concentration. The ρ_0 is ~0.3 $m\Omega$ cm for the pure SmFeAsO_{0.85}F_{0.15} system and increases sharply with the Ru substitution reaching a maximum value of about 2 m Ω cm for x = 0.25 while the T_c decreases [21]. With further Ru substitution the ρ_0 decreases by half at $x = 0.5 \ (\rho_0 \sim 2 \ \text{m}\Omega \ \text{cm})$ and has a similar value of $\rho_0 \sim 0.3 \ \text{m}\Omega \ \text{cm}$ for the x = 1. Therefore, it appears that the impurity scattering from the substituted ruthenium being dominant to describe the transport phenomena for $x \le 0.25$.

On the other hand, the larger static disorder of the Fe-As bonds in x = 0.5 sample ($\sigma_0^2 \sim 0.0026$ Å²), albeit with the force constant being similar to the other samples (4.83 eV/Å²), suggests that some different mechanism should be active to describe the electronic transport, i.e. decreased ρ_0 and the T_c for $x \ge 0.25$. In addition, the force constant for the Ru-As distance remains the same for x = 0.25 and 0.5 samples, (6.04 and 6.07 eV/Å², respectively). Therefore, it is likely that the title system is phase separated even at x = 0.25, and the reduced ρ_0 from x = 0.25 to x = 0.5is merely due to the increased density of states with increasing Ru because of more extended Ru 4d states than Fe 3d, consistent with the density functional theory calculations [21]. It should be mentioned that the active and spacer layers are getting decoupled and thinner with the Ru substitution [19], i.e., electronically the system contains active FeAs layers which have poorer screening from the spacer layers, and hence can suffer phase separation as the case of ternary FeSe_{1-x}Te_x [15]. Since the characteristic length scale of EXAFS is about a nanometer, it can be fairly argued that the observed phase separation is at a nanometer length scale, that is consistent with μ SR measurements [22] on the similar system. It is also interesting to note that similar nanoscale textures have been observed in the Ru-substituted BaFe₂As₂ (122) system by NMR experiments due to inhomogeneous destruction of antiferromagnetic order by Ru substitution [32].

We can also notice that the σ_i^2 for the Ru-As bondlength manifests an upturn at a temperature ~ 40 K (Fig. 4). This appears to be consistent with the anomaly observed in zero field μ SR measurements, sensitive to short range magnetic order, revealing similar change in the Ru substituted 1111-system [22]. However, the observed change is very small to be stressed further and more experimental work is needed before it can be argued if the short range magnetic order is coupled to the charge and atomic displacements for particular Ru concentrations.

In summary, we have studied temperature dependent local structure of $\text{SmFe}_{1-x} \text{Ru}_x \text{AsO}_{0.85} \text{F}_{0.15}$ system for varying Ru concentration by As K-edge EXAFS. We find that Ru substitution effect is mainly confined to the electronically active FeAs layer, and the Ru substituted system has different Fe-As and Ru-As distances. The force constants of the Fe-As and Ru-As bonds do not show any change with the Ru concentration, indicating coexisting electronic phases in the isoelectronic substitution. The static disorder in the Fe-As bonds remains unchanged as the bond strength for $x \leq$ 0.25, suggesting that the transport properties of the system should be described mainly by the impurity scattering in FeAs layers. With further Ru substitution, the extended Ru 4d states affects substantially the electronic density of states at the Fermi level, and hence the transport phenomena. On the basis of present results we can conclude that upon isoelectric substitution the title system breaks down into coexisting nanoscale electronic phases due to the frustration of interlayer atomic correlations.

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